## NSN 5962-01-163-8904

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high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-163-8904

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inc	hes and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power	Dissipation Rating:
739.0 milliwatts	
Operating Tempu	rature Range:
-55.0/+125.0 degre	es celsius
Storage Tempura	ture Range:
-65.0/+150.0 degre	nes celsius
End Application:	
Radar system an/f	os-117
Features Provide	d:
Hermetically seale	d and burn in and bipolar and schottky and programmable and w/enable and w/active pull-up
Inclosure Materia	:
Ceramic	
Inclosure Configu	iration:
Dual-in-line	
Output Logic For	n:
Transistor-transisto	or logic
Input Circuit Patte	ern:
10 input	
Case Outline Sou	rce And Designator:
D-2 mil-m-38510	
Terminal Surface	Treatment:
Solder	
Voltage Rating A	nd Type Per Characteristic:
5.5 volts power so	urce
Time Rating Per 0	Chacteristic:
75.00 nanosecond	s propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, h
output	
Memory Device T	ype:
Rom	
Memory Capacity	:
Unknown	
Terminal Type An	d Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

## NSN 5962-01-163-8904

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## Demilitarization:

Yes - demil/mli

Fiig:

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